Transmissive Sensor

FEATURES

- Choice of phototransistor or photodarlington output
- 0.060 in.(1.52 mm)dia. detector aperture
- 0.125 in.(3.18 mm) slot width
- 18.0 in.(457 mm) min. 22 AWG UL 1429 wire leads



DESCRIPTION

The HOA1881 series consists of an infrared emitting diode facing an NPN silicon phototransistor (HOA1881-011, -012) or photodarlington (HOA1881-013) encased in a black thermoplastic housing. Detector switching takes place whenever an opaque object passes through the slot between emitter and detector. The lead wires of minimum length 18.0 in.(457 mm) provide alternate electrical connection when PC board mounting is not possible. The HOA1881 series employs plastic molded components. For additional component information see SEP8506, SDP8406, and SDP8106.

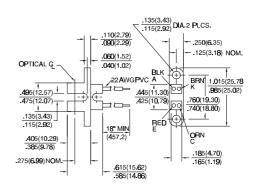
Housing material is nylon. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

Wire color code and functions are:

Black - IRED Anode Orange - Detector Collector Brown - IRED Cathode Red - Detector Emitter

OUTLINE DIMENSIONS in inches (mm)

3 plc decimals ±0.010(0.25) 2 plc decimals ±0.020(0.51)



DIM_052.cdr



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ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	VF			1.6	V	I _F =20 mA
Reverse Leakage Current	l _R			10	μΑ	V _R =3 V
DETECTOR Collector-Emitter Breakdown Voltage HOA1881-011, -012	V _(BR) ceo	30			V	Ic=100 μA
HOA1881-013		15				
Emitter-Collector Breakdown Voltage	V _{(BR)ECO}	5.0			V	I _E =100 μA
Collector Dark Current HOA1881-011, -012 HOA1881-013	Iceo			100 250	nA	V _{CE} =10 V I _F =0
COUPLED CHARACTERISTICS On-State Collector Current HOA1881-011 HOA1881-012 HOA1881-013	I _{C(ON)}	0.3 1.8 4.0			mA	V _{CE} =5 V I _F =20 mA
Collector-Emitter Saturation Voltage HOA1881-011 HOA1881-012 HOA1881-013	VCE(SAT)			0.4 0.4 1.1	V	I _F =20 mA I _C =40 μA I _C =230 μA I _C =500 μA
Rise And Fall Time HOA1881-011, -012 HOA1881-013	t _r , t _f		15 75		μs	V_{CC} =5 V, I _C =1 mA R_L =1000 Ω R_L =100 Ω

ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted)

Operating Temperature Range -40°C to 85°C

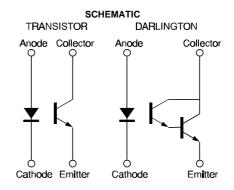
Storage Temperature Range -40°C to 85°C

Soldering Temperature (5 sec) 240°C

IR EMITTER

Power Dissipation 100 mW ⁽¹⁾
Reverse Voltage 3 V
Continuous Forward Current 50 mA

DETECTORTRANS.DARLINGTONCollector-Emitter Voltage30 V15 VEmitter-Collector Voltage5 V5 VPower Dissipation100 mW (¹)100 mW (¹)Collector DC Current30 mA30 mA

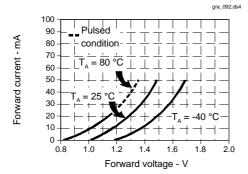


Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

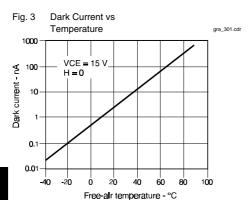
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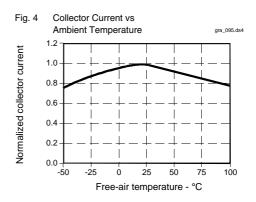
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Non-Saturated Switching Time vs Load Resistance 1000 ▤◾▦▦ Response time - µs 100 Photodarlington = = = = Phototransistor ŦI#I# 10 100 1000 10000 Load resistance - Ohms





All Performance Curves Show Typical Values

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